ispMACH® 4000V/B/C/Z Family

3.3V/2.5V/1.8V In-System Programmable SuperFAST™ High Density PLDs

Coolest Power
Coolest Price™

Features

■ High Performance
- f_{MAX} = 400MHz maximum operating frequency
- t_{PD} = 2.5ns propagation delay
- Up to four global clock pins with programmable clock polarity control
- Up to 80 PTs per output

■ Ease of Design
- Enhanced macrocells with individual clock, reset, preset and clock enable controls
- Up to four global OE controls
- Individual local OE control per I/O pin
- Excellent First-Time-Fit™ and refit
- Fast path, SpeedLocking™ Path, and wide-PT path
- Wide input gating (36 input logic blocks) for fast counters, state machines and address decoders

■ Zero Power (ispMACH 4000Z) and Low Power (ispMACH 4000V/B/C)
- Typical static current 10μA (4032Z)
- Typical static current 1.3mA (4000C)
- 1.8V core low dynamic power
- ispMACH 4000Z operational down to 1.6V V_{CC}

■ Broad Device Offering
- Multiple temperature range support
  - Commercial: 0 to 90°C junction (T_j)
  - Industrial: -40 to 105°C junction (T_j)
  - Extended: -40 to 130°C junction (T_j)
    - For AEC-Q100 compliant devices, refer to LA-ispMACH 4000V/Z Automotive Data Sheet

■ Easy System Integration
- Superior solution for power sensitive consumer applications
- Operation with 3.3V, 2.5V or 1.8V LVCMOS I/O
- Operation with 3.3V (4000V), 2.5V (4000B) or 1.8V (4000C/Z) supplies
- 5V tolerant I/O for LVCMOS 3.3, LVTTL, and PCI interfaces
- Hot-socketing
- Open-drain capability
- Input pull-up, pull-down or bus-keeper
- Programmable output slew rate
- 3.3V PCI compatible
- IEEE 1149.1 boundary scan testable
- 3.3V/2.5V/1.8V In-System Programmable (ISP™) using IEEE 1532 compliant interface
- I/O pins with fast setup path
- Lead-free package options

Table 1. ispMACH 4000V/B/C Family Selection Guide

	ispMACH 4032V/B/C	ispMACH 4064V/B/C	ispMACH 4128V/B/C	ispMACH 4256V/B/C	ispMACH 4384V/B/C	ispMACH 4512V/B/C
Macrocells	32	64	128	256	384	512
I/O + Dedicated Inputs	30+2/32+4	30+2/32+4/ 64+10	64+10/92+4/ 96+4	64+10/96+14/ 128+4/160+4	128+4/192+4	128+4/208+4
t_{PD} (ns)	2.5	2.5	2.7	3.0	3.5	3.5
t_S (ns)	1.8	1.8	1.8	2.0	2.0	2.0
t_{CO} (ns)	2.2	2.2	2.7	2.7	2.7	2.7
f_{MAX} (MHz)	400	400	333	322	322	322
Supply Voltages (V)	3.3/2.5/1.8V	3.3/2.5/1.8V	3.3/2.5/1.8V	3.3/2.5/1.8V	3.3/2.5/1.8V	3.3/2.5/1.8V
Pins/Package	44 TQFP 48 TQFP	44 TQFP 48 TQFP 100 TQFP	100 TQFP 128 TQFP 144 TQFP[1]	100 TQFP 144 TQFP[1] 176 TQFP 256 ftBGA[2]/ fpBGA[2, 3]	176 TQFP 256 ftBGA/ fpBGA[3]	176 TQFP 256 ftBGA/ fpBGA[3]

1. 3.3V (4000V) only.
2. 128-I/O and 160-I/O configurations.
3. Use 256 ftBGA package for all new designs. Refer to PCN#14A-07 for 256 fpBGA package discontinuance.

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Table 2. ispMACH 4000Z Family Selection Guide

	ispMACH 4032ZC	ispMACH 4064ZC	ispMACH 4128ZC	ispMACH 4256ZC
Macrocells	32	64	128	256
I/O + Dedicated Inputs	32+4/32+4	32+4/32+12/ 64+10/64+10	64+10/96+4	64+10/96+6/ 128+4
t_{PD} (ns)	3.5	3.7	4.2	4.5
t_S (ns)	2.2	2.5	2.7	2.9
t_{CO} (ns)	3.0	3.2	3.5	3.8
f_{MAX} (MHz)	267	250	220	200
Supply Voltage (V)	1.8	1.8	1.8	1.8
Max. Standby Icc (µA)	20	25	35	55
Pins/Package	48 TQFP 56 csBGA	48 TQFP 56 csBGA 100 TQFP 132 csBGA	100 TQFP 132csBGA	100 TQFP 132 csBGA 176 TQFP

ispMACH 4000 Introduction

The high performance ispMACH 4000 family from Lattice offers a SuperFAST CPLD solution. The family is a blend of Lattice's two most popular architectures: the ispLSI® 2000 and ispMACH 4A. Retaining the best of both families, the ispMACH 4000 architecture focuses on significant innovations to combine the highest performance with low power in a flexible CPLD family.

The ispMACH 4000 combines high speed and low power with the flexibility needed for ease of design. With its robust Global Routing Pool and Output Routing Pool, this family delivers excellent First-Time-Fit, timing predictability, routing, pin-out retention and density migration.

The ispMACH 4000 family offers densities ranging from 32 to 512 macrocells. There are multiple density-I/O combinations in Thin Quad Flat Pack (TQFP), Chip Scale BGA (csBGA) and Fine Pitch Thin BGA (ftBGA) packages ranging from 44 to 256 pins/balls. Table 1 shows the macrocell, package and I/O options, along with other key parameters.

The ispMACH 4000 family has enhanced system integration capabilities. It supports 3.3V (4000V), 2.5V (4000B) and 1.8V (4000C/Z) supply voltages and 3.3V, 2.5V and 1.8V interface voltages. Additionally, inputs can be safely driven up to 5.5V when an I/O bank is configured for 3.3V operation, making this family 5V tolerant. The ispMACH 4000 also offers enhanced I/O features such as slew rate control, PCI compatibility, bus-keeper latches, pull-up resistors, pull-down resistors, open drain outputs and hot socketing. The ispMACH 4000 family members are 3.3V/ 2.5V/1.8V in-system programmable through the IEEE Standard 1532 interface. IEEE Standard 1149.1 boundary scan testing capability also allows product testing on automated test equipment. The 1532 interface signals TCK, TMS, TDI and TDO are referenced to V_{CC} (logic core).

Overview

The ispMACH 4000 devices consist of multiple 36-input, 16-macrocell Generic Logic Blocks (GLBs) interconnected by a Global Routing Pool (GRP). Output Routing Pools (ORPs) connect the GLBs to the I/O Blocks (IOBs), which contain multiple I/O cells. This architecture is shown in Figure 1.

Absolute Maximum Ratings[1, 2, 3]

	ispMACH 4000C/Z (1.8V)	ispMACH 4000B (2.5V)	ispMACH 4000V (3.3V)
Supply Voltage (V_{CC})	-0.5 to 2.5V	-0.5 to 5.5V	-0.5 to 5.5V
Output Supply Voltage (V_{CCO})	-0.5 to 4.5V	-0.5 to 4.5V	-0.5 to 4.5V
Input or I/O Tristate Voltage Applied[4, 5]	-0.5 to 5.5V	-0.5 to 5.5V	-0.5 to 5.5V
Storage Temperature	-65 to 150°C	-65 to 150°C	-65 to 150°C
Junction Temperature (T_j) with Power Applied . . .	-55 to 150°C	-55 to 150°C	-55 to 150°C

1. Stress above those listed under the "Absolute Maximum Ratings" may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.
2. Compliance with Lattice *Thermal Management* document is required.
3. All voltages referenced to GND.
4. Undershoot of -2V and overshoot of (V_{IH} (MAX) + 2V), up to a total pin voltage of 6.0V, is permitted for a duration of < 20ns.
5. Maximum of 64 I/Os per device with VIN > 3.6V is allowed.

Recommended Operating Conditions

Symbol	Parameter		Min.	Max.	Units
V_{CC}	Supply Voltage for 1.8V Devices	ispMACH 4000C	1.65	1.95	V
		ispMACH 4000Z	1.7	1.9	V
		ispMACH 4000Z, Extended Functional Voltage Operation	1.6[1, 2]	1.9	V
	Supply Voltage for 2.5V Devices		2.3	2.7	V
	Supply Voltage for 3.3V Devices		3.0	3.6	V
T_j	Junction Temperature (Commercial)		0	90	C
	Junction Temperature (Industrial)		-40	105	C
	Junction Temperature (Extended)		-40	130	C

1. Devices operating at 1.6V can expect performance degradation up to 35%.
2. Applicable for devices with 2004 date codes and later. Contact factory for ordering instructions.

Erase Reprogram Specifications

Parameter	Min.	Max.	Units
Erase/Reprogram Cycle	1,000	—	Cycles

Note: Valid over commercial temperature range.

Hot Socketing Characteristics[1,2,3]

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
I_{DK}	Input or I/O Leakage Current	0 ≤ V_{IN} ≤ 3.0V, Tj = 105°C	—	±30	±150	µA
		0 ≤ V_{IN} ≤ 3.0V, Tj = 130°C	—	±30	±200	µA

1. Insensitive to sequence of V_{CC} or V_{CCO}. However, assumes monotonic rise/fall rates for V_{CC} and V_{CCO}, provided (V_{IN} - V_{CCO}) ≤ 3.6V.
2. 0 < V_{CC} < V_{CC} (MAX), 0 < V_{CCO} < V_{CCO} (MAX).
3. I_{DK} is additive to I_{PU}, I_{PD} or I_{BH}. Device defaults to pull-up until fuse circuitry is active.

I/O Recommended Operating Conditions

Standard	V_{CCO} (V)[1]	
	Min.	Max.
LVTTL	3.0	3.6
LVCMOS 3.3	3.0	3.6
Extended LVCMOS 3.3[2]	2.7	3.6
LVCMOS 2.5	2.3	2.7
LVCMOS 1.8	1.65	1.95
PCI 3.3	3.0	3.6

1. Typical values for V_{CCO} are the average of the min. and max. values.
2. ispMACH 4000Z only.

DC Electrical Characteristics

Over Recommended Operating Conditions

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
I_{IL}, I_{IH}[1, 4]	Input Leakage Current (ispMACH 4000Z)	$0 \le V_{IN} < V_{CCO}$	—	0.5	1	μA
I_{IH}[1]	Input High Leakage Current (ispMACH 4000Z)	$V_{CCO} < V_{IN} \le 5.5V$	—	—	10	μA
I_{IL}, I_{IH}[1]	Input Leakage Current (ispMACH 4000V/B/C)	$0 \le V_{IN} \le 3.6V$, $T_j = 105°C$	—	—	10	μA
		$0 \le V_{IN} \le 3.6V$, $T_j = 130°C$	—	—	15	μA
I_{IH}[1,2]	Input High Leakage Current (ispMACH 4000V/B/C)	$3.6V < V_{IN} \le 5.5V$, $T_j = 105°C$ $3.0V \le V_{CCO} \le 3.6V$	—	—	20	μA
		$3.6V < V_{IN} \le 5.5V$, $T_j = 130°C$ $3.0V \le V_{CCO} \le 3.6V$	—	—	50	μA
I_{PU}	I/O Weak Pull-up Resistor Current (ispMACH 4000Z)	$0 \le V_{IN} \le 0.7V_{CCO}$	-30	—	-150	μA
	I/O Weak Pull-up Resistor Current (ispMACH 4000V/B/C)	$0 \le V_{IN} \le 0.7V_{CCO}$	-30	—	-200	μA
I_{PD}	I/O Weak Pull-down Resistor Current	V_{IL} (MAX) $\le V_{IN} \le V_{IH}$ (MIN)	30	—	150	μA
I_{BHLS}	Bus Hold Low Sustaining Current	$V_{IN} = V_{IL}$ (MAX)	30	—	—	μA
I_{BHHS}	Bus Hold High Sustaining Current	$V_{IN} = 0.7\ V_{CCO}$	-30	—	—	μA
I_{BHLO}	Bus Hold Low Overdrive Current	$0V \le V_{IN} \le V_{BHT}$	—	—	150	μA
I_{BHHO}	Bus Hold High Overdrive Current	$V_{BHT} \le V_{IN} \le V_{CCO}$	—	—	-150	μA
V_{BHT}	Bus Hold Trip Points	—	$V_{CCO} * 0.35$	—	$V_{CCO} * 0.65$	V
C_1	I/O Capacitance[3]	V_{CCO} = 3.3V, 2.5V, 1.8V	—	8	—	pf
		V_{CC} = 1.8V, V_{IO} = 0 to V_{IH} (MAX)	—		—	
C_2	Clock Capacitance[3]	V_{CCO} = 3.3V, 2.5V, 1.8V	—	6	—	pf
		V_{CC} = 1.8V, V_{IO} = 0 to V_{IH} (MAX)	—		—	
C_3	Global Input Capacitance[3]	V_{CCO} = 3.3V, 2.5V, 1.8V	—	6	—	pf
		V_{CC} = 1.8V, V_{IO} = 0 to V_{IH} (MAX)	—		—	

1. Input or I/O leakage current is measured with the pin configured as an input or as an I/O with the output driver tristated. It is not measured with the output driver active. Bus maintenance circuits are disabled.
2. 5V tolerant inputs and I/O should only be placed in banks where $3.0V \le V_{CCO} \le 3.6V$.
3. $T_A = 25°C$, f = 1.0MHz.
4. I_{IH} excursions of up to 1.5μA maximum per pin above the spec limit may be observed for certain voltage conditions on no more than 10% of the device's I/O pins.

Supply Current, ispMACH 4000V/B/C

Over Recommended Operating Conditions

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
ispMACH 4032V/B/C						
ICC[1,2,3]	Operating Power Supply Current	Vcc = 3.3V	—	11.8	—	mA
		Vcc = 2.5V	—	11.8	—	mA
		Vcc = 1.8V	—	1.8	—	mA
ICC[4]	Standby Power Supply Current	Vcc = 3.3V	—	11.3	—	mA
		Vcc = 2.5V	—	11.3	—	mA
		Vcc = 1.8V	—	1.3	—	mA
ispMACH 4064V/B/C						
ICC[1,2,3]	Operating Power Supply Current	Vcc = 3.3V	—	12	—	mA
		Vcc = 2.5V	—	12	—	mA
		Vcc = 1.8V	—	2	—	mA
ICC[5]	Standby Power Supply Current	Vcc = 3.3V	—	11.5	—	mA
		Vcc = 2.5V	—	11.5	—	mA
		Vcc = 1.8V	—	1.5	—	mA
ispMACH 4128V/B/C						
ICC[1,2,3]	Operating Power Supply Current	Vcc = 3.3V	—	12	—	mA
		Vcc = 2.5V	—	12	—	mA
		Vcc = 1.8V	—	2	—	mA
ICC[4]	Standby Power Supply Current	Vcc = 3.3V	—	11.5	—	mA
		Vcc = 2.5V	—	11.5	—	mA
		Vcc = 1.8V	—	1.5	—	mA
ispMACH 4256V/B/C						
I_{CC}[1,2,3]	Operating Power Supply Current	Vcc = 3.3V	—	12.5	—	mA
		Vcc = 2.5V	—	12.5	—	mA
		Vcc = 1.8V	—	2.5	—	mA
I_{CC}[4]	Standby Power Supply Current	Vcc = 3.3V	—	12	—	mA
		Vcc = 2.5V	—	12	—	mA
		Vcc = 1.8V	—	2	—	mA
ispMACH 4384V/B/C						
I_{CC}[1,2,3]	Operating Power Supply Current	Vcc = 3.3V	—	13.5	—	mA
		Vcc = 2.5V	—	13.5	—	mA
		Vcc = 1.8V	—	3.5	—	mA
I_{CC}[4]	Standby Power Supply Current	Vcc = 3.3V	—	12.5	—	mA
		Vcc = 2.5V	—	12.5	—	mA
		Vcc = 1.8V	—	2.5	—	mA
ispMACH 4512V/B/C						
I_{CC}[1,2,3]	Operating Power Supply Current	Vcc = 3.3V	—	14	—	mA
		Vcc = 2.5V	—	14	—	mA
		Vcc = 1.8V	—	4	—	mA

Supply Current, ispMACH 4000V/B/C (Cont.)

Over Recommended Operating Conditions

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
I_{CC}[4]	Standby Power Supply Current	Vcc = 3.3V	—	13	—	mA
		Vcc = 2.5V	—	13	—	mA
		Vcc = 1.8V	—	3	—	mA

1. T_A = 25°C, frequency = 1.0 MHz.
2. Device configured with 16-bit counters.
3. I_{CC} varies with specific device configuration and operating frequency.
4. T_A = 25°C

Supply Current, ispMACH 4000Z

Over Recommended Operating Conditions

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
ispMACH 4032ZC						
ICC[1, 2, 3, 5]	Operating Power Supply Current	Vcc = 1.8V, T_A = 25°C	—	50	—	µA
		Vcc = 1.9V, T_A = 70°C	—	58	—	µA
		Vcc = 1.9V, T_A = 85°C	—	60	—	µA
		Vcc = 1.9V, T_A = 125°C	—	70	—	µA
ICC[4, 5]	Standby Power Supply Current	Vcc = 1.8V, T_A = 25°C	—	10	—	µA
		Vcc = 1.9V, T_A = 70°C	—	13	20	µA
		Vcc = 1.9V, T_A = 85°C	—	15	25	µA
		Vcc = 1.9V, T_A = 125°C	—	22	—	µA
ispMACH 4064ZC						
ICC[1, 2, 3, 5]	Operating Power Supply Current	Vcc = 1.8V, T_A = 25°C	—	80	—	µA
		Vcc = 1.9V, T_A = 70°C	—	89	—	µA
		Vcc = 1.9V, T_A = 85°C	—	92	—	µA
		Vcc = 1.9V, T_A = 125°C	—	109	—	µA
ICC[4, 5]	Standby Power Supply Current	Vcc = 1.8V, T_A = 25°C	—	11	—	µA
		Vcc = 1.9V, T_A = 70°C	—	15	25	µA
		Vcc = 1.9V, T_A = 85°C	—	18	35	µA
		Vcc = 1.9V, T_A = 125°C	—	37	—	µA
ispMACH 4128ZC						
ICC[1, 2, 3, 5]	Operating Power Supply Current	Vcc = 1.8V, T_A = 25°C	—	168	—	µA
		Vcc = 1.9V, T_A = 70°C	—	190	—	µA
		Vcc = 1.9V, T_A = 85°C	—	195	—	µA
		Vcc = 1.9V, T_A = 125°C	—	212	—	µA
ICC[4, 5]	Standby Power Supply Current	Vcc = 1.8V, T_A = 25°C	—	12	—	µA
		Vcc = 1.9V, T_A = 70°C	—	16	35	µA
		Vcc = 1.9V, T_A = 85°C	—	19	50	µA
		Vcc = 1.9V, T_A = 125°C	—	42	—	µA

I/O DC Electrical Characteristics

Over Recommended Operating Conditions

Standard	V_{IL}		V_{IH}		V_{OL}	V_{OH}	I_{OL}[1]	I_{OH}[1]
	Min (V)	Max (V)	Min (V)	Max (V)	Max (V)	Min (V)	(mA)	(mA)
LVTTL	-0.3	0.80	2.0	5.5	0.40	V_{CCO} - 0.40	8.0	-4.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
LVCMOS 3.3	-0.3	0.80	2.0	5.5	0.40	V_{CCO} - 0.40	8.0	-4.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
LVCMOS 2.5	-0.3	0.70	1.70	3.6	0.40	V_{CCO} - 0.40	8.0	-4.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
LVCMOS 1.8 (4000V/B)	-0.3	0.63	1.17	3.6	0.40	V_{CCO} - 0.45	2.0	-2.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
LVCMOS 1.8 (4000C/Z)	-0.3	$0.35 * V_{CC}$	$0.65 * V_{CC}$	3.6	0.40	V_{CCO} - 0.45	2.0	-2.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
PCI 3.3 (4000V/B)	-0.3	1.08	1.5	5.5	$0.1\ V_{CCO}$	$0.9\ V_{CCO}$	1.5	-0.5
PCI 3.3 (4000C/Z)	-0.3	$0.3 * 3.3 * (V_{CC} / 1.8)$	$0.5 * 3.3 * (V_{CC} / 1.8)$	5.5	$0.1\ V_{CCO}$	$0.9\ V_{CCO}$	1.5	-0.5

1. The average DC current drawn by I/Os between adjacent bank GND connections, or between the last GND in an I/O bank and the end of the I/O bank, as shown in the logic signals connection table, shall not exceed n*8mA. Where n is the number of I/Os between bank GND connections or between the last GND in a bank and the end of a bank.

ispMACH 4000V/B/C External Switching Characteristics (Cont.)

Over Recommended Operating Conditions

Parameter	Description[1, 2, 3]	-5 Min.	-5 Max.	-75 Min.	-75 Max.	-10 Min.	-10 Max.	Units
t_{PD}	5-PT bypass combinatorial propagation delay	—	5.0	—	7.5	—	10.0	ns
t_{PD_MC}	20-PT combinatorial propagation delay through macrocell	—	5.5	—	8.0	—	10.5	ns
t_S	GLB register setup time before clock	3.0	—	4.5	—	5.5	—	ns
t_{ST}	GLB register setup time before clock with T-type register	3.2	—	4.7	—	5.5	—	ns
t_{SIR}	GLB register setup time before clock, input register path	1.2	—	1.7	—	1.7	—	ns
t_{SIRZ}	GLB register setup time before clock with zero hold	2.2	—	2.7	—	2.7	—	ns
t_H	GLB register hold time after clock	0.0	—	0.0	—	0.0	—	ns
t_{HT}	GLB register hold time after clock with T-type register	0.0	—	0.0	—	0.0	—	ns
t_{HIR}	GLB register hold time after clock, input register path	1.0	—	1.0	—	1.0	—	ns
t_{HIRZ}	GLB register hold time after clock, input register path with zero hold	0.0	—	0.0	—	0.0	—	ns
t_{CO}	GLB register clock-to-output delay	—	3.4	—	4.5	—	6.0	ns
t_R	External reset pin to output delay	—	6.3	—	9.0	—	10.5	ns
t_{RW}	External reset pulse duration	2.0	—	4.0	—	4.0	—	ns
$t_{PTOE/DIS}$	Input to output local product term output enable/disable	—	7.0	—	9.0	—	10.5	ns
$t_{GPTOE/DIS}$	Input to output global product term output enable/disable	—	9.0	—	10.3	—	12.0	ns
$t_{GOE/DIS}$	Global OE input to output enable/disable	—	5.0	—	7.0	—	8.0	ns
t_{CW}	Global clock width, high or low	2.2	—	3.3	—	4.0	—	ns
t_{GW}	Global gate width low (for low transparent) or high (for high transparent)	2.2	—	3.3	—	4.0	—	ns
t_{WIR}	Input register clock width, high or low	2.2	—	3.3	—	4.0	—	ns
f_{MAX}[4]	Clock frequency with internal feedback	227	—	168	—	125	—	MHz
f_{MAX} (Ext.)	Clock frequency with external feedback, $[1/(t_S + t_{CO})]$	156	—	111	—	86	—	MHz

1. Timing numbers are based on default LVCMOS 1.8 I/O buffers. Use timing adjusters provided to calculate other standards. Timing v.3.2
2. Measured using standard switching circuit, assuming GRP loading of 1 and 1 output switching.
3. Pulse widths and clock widths less than minimum will cause unknown behavior.
4. Standard 16-bit counter using GRP feedback.

ispMACH 4000V/B/C Internal Timing Parameters

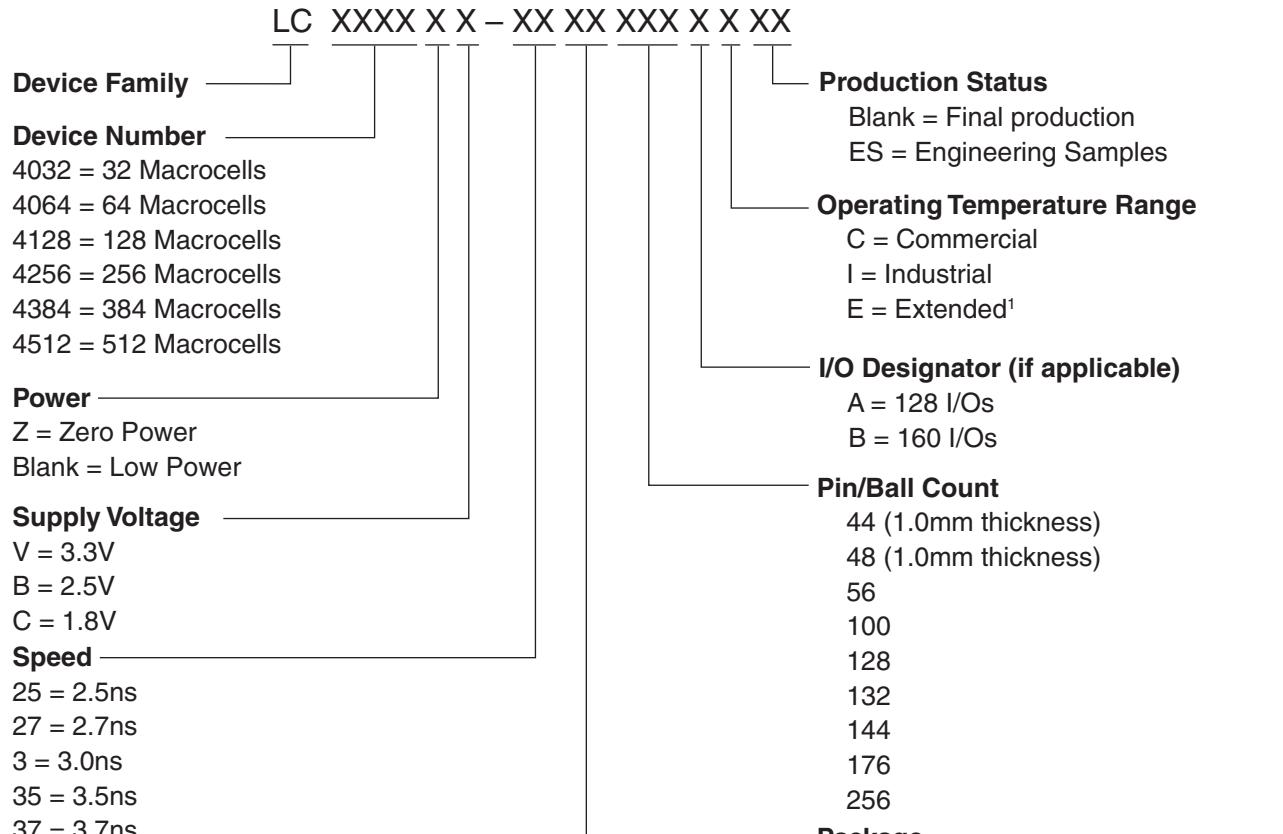## Over Recommended Operating Conditions

Parameter	Description	-5 Min.	-5 Max.	-75 Min.	-75 Max.	-10 Min.	-10 Max.	Units
In/Out Delays								
t_{IN}	Input Buffer Delay	—	0.95	—	1.50	—	2.00	ns
t_{GOE}	Global OE Pin Delay	—	4.04	—	6.04	—	7.04	ns
t_{GCLK_IN}	Global Clock Input Buffer Delay	—	1.83	—	2.28	—	3.28	ns
t_{BUF}	Delay through Output Buffer	—	1.00	—	1.50	—	1.50	ns
t_{EN}	Output Enable Time	—	0.96	—	0.96	—	0.96	ns
t_{DIS}	Output Disable Time	—	0.96	—	0.96	—	0.96	ns
Routing/GLB Delays								
t_{ROUTE}	Delay through GRP	—	1.51	—	2.26	—	3.26	ns
t_{MCELL}	Macrocell Delay	—	1.05	—	1.45	—	1.95	ns
t_{INREG}	Input Buffer to Macrocell Register Delay	—	0.56	—	0.96	—	1.46	ns
t_{FBK}	Internal Feedback Delay	—	0.00	—	0.00	—	0.00	ns
t_{PDb}	5-PT Bypass Propagation Delay	—	1.54	—	2.24	—	3.24	ns
t_{PDi}	Macrocell Propagation Delay	—	0.94	—	1.24	—	1.74	ns
Register/Latch Delays								
t_S	D-Register Setup Time (Global Clock)	1.32	—	1.57	—	1.57	—	ns
t_{S_PT}	D-Register Setup Time (Product Term Clock)	1.32	—	1.32	—	1.32	—	ns
t_{ST}	T-Register Setup Time (Global Clock)	1.52	—	1.77	—	1.77	—	ns
t_{ST_PT}	T-Register Setup Time (Product Term Clock)	1.32	—	1.32	—	1.32	—	ns
t_H	D-Register Hold Time	1.68	—	2.93	—	3.93	—	ns
t_{HT}	T-Register Hold Time	1.68	—	2.93	—	3.93	—	ns
t_{SIR}	D-Input Register Setup Time (Global Clock)	1.52	—	1.57	—	1.57	—	ns
t_{SIR_PT}	D-Input Register Setup Time (Product Term Clock)	1.45	—	1.45	—	1.45	—	ns
t_{HIR}	D-Input Register Hold Time (Global Clock)	0.68	—	1.18	—	1.18	—	ns
t_{HIR_PT}	D-Input Register Hold Time (Product Term Clock)	0.68	—	1.18	—	1.18	—	ns
t_{COi}	Register Clock to Output/Feedback MUX Time	—	0.52	—	0.67	—	1.17	ns
t_{CES}	Clock Enable Setup Time	2.25	—	2.25	—	2.25	—	ns
t_{CEH}	Clock Enable Hold Time	1.88	—	1.88	—	1.88	—	ns
t_{SL}	Latch Setup Time (Global Clock)	1.32	—	1.57	—	1.57	—	ns
t_{SL_PT}	Latch Setup Time (Product Term Clock)	1.32	—	1.32	—	1.32	—	ns
t_{HL}	Latch Hold Time	1.17	—	1.17	—	1.17	—	ns
t_{GOi}	Latch Gate to Output/Feedback MUX Time	—	0.33	—	0.33	—	0.33	ns
t_{PDLi}	Propagation Delay through Transparent Latch to Output/Feedback MUX	—	0.25	—	0.25	—	0.25	ns
t_{SRi}	Asynchronous Reset or Set to Output/Feedback MUX Delay	0.28	—	0.28	—	0.28	—	ns
t_{SRR}	Asynchronous Reset or Set Recovery Time	1.67	—	1.67	—	1.67	—	ns
Control Delays								
t_{BCLK}	GLB PT Clock Delay	—	1.12	—	1.12	—	0.62	ns
t_{PTCLK}	Macrocell PT Clock Delay	—	0.87	—	0.87	—	0.87	ns
t_{BSR}	GLB PT Set/Reset Delay	—	1.83	—	1.83	—	1.83	ns
t_{PTSR}	Macrocell PT Set/Reset Delay	—	2.51	—	3.41	—	3.41	ns

ispMACH 4000V/B/C Internal Timing Parameters (Cont.)

Over Recommended Operating Conditions

Parameter	Description	-5		-75		-10		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
t_{GPTOE}	Global PT OE Delay	—	5.58	—	5.58	—	5.78	ns
t_{PTOE}	Macrocell PT OE Delay	—	3.58	—	4.28	—	4.28	ns

Timing v.3.2

Note: Internal Timing Parameters are not tested and are for reference only. Refer to Timing Model in this data sheet for further details.

Part Number Description

LC XXXX X X – XX XX XXX X X XX

Device Family

Device Number
4032 = 32 Macrocells
4064 = 64 Macrocells
4128 = 128 Macrocells
4256 = 256 Macrocells
4384 = 384 Macrocells
4512 = 512 Macrocells

Power
Z = Zero Power
Blank = Low Power

Supply Voltage
V = 3.3V
B = 2.5V
C = 1.8V

Speed
25 = 2.5ns
27 = 2.7ns
3 = 3.0ns
35 = 3.5ns
37 = 3.7ns
42 = 4.2ns
45 = 4.5ns
5 = 5.0ns
75 = 7.5ns
10 = 10.0ns

Production Status
Blank = Final production
ES = Engineering Samples

Operating Temperature Range
C = Commercial
I = Industrial
E = Extended[1]

I/O Designator (if applicable)
A = 128 I/Os
B = 160 I/Os

Pin/Ball Count
44 (1.0mm thickness)
48 (1.0mm thickness)
56
100
128
132
144
176
256

Package
T = TQFP   TN = Lead-free TQFP
FT = ftBGA   FTN= Lead-free ftBGA
F = fpBGA[2]   FN = Lead-free fpBGA[2]
M = csBGA   MN = Lead-free csBGA

1. For automotive AEC-Q100 compliant devices, refer to the LA-ispMACH 4000V/Z Automotive Family Data Sheet (DS1017).

2. Use ftBGA package. fpBGA package devices have been discontinued via PCN#14A-07.

ispMACH 4000 Family Speed Grade Offering

	-25	-27	-3	-35	-37	-42	-45	-5		-75			-10
	Com	Com	Com	Com	Com	Com	Com	Com	Ind	Com	Ind	Ext	Ind
ispMACH 4032V/B/C	✔							✔	✔	✔	✔	✔[1]	✔
ispMACH 4064V/B/C	✔							✔	✔	✔	✔	✔[1]	✔
ispMACH 4128V/B/C		✔						✔	✔	✔	✔	✔[1]	✔
ispMACH 4256V/B/C			✔					✔	✔	✔	✔	✔	✔
ispMACH 4384V/B/C				✔				✔	✔	✔	✔		✔
ispMACH 4512V/B/C				✔				✔	✔	✔	✔		✔
ispMACH 4032ZC				✔				✔	✔	✔	✔	✔[1]	
ispMACH 4064ZC					✔			✔	✔	✔	✔	✔[1]	
ispMACH 4128ZC						✔				✔	✔	✔[1]	
ispMACH 4256ZC							✔			✔	✔	✔	

1. 3.3V only.

ispMACH 4000B (2.5V) Lead-Free Commercial Devices

Device	Part Number	Macrocells	Voltage	t_{PD}	Package	Pin/Ball Count	I/O	Grade
LC4032B	LC4032B-25TN48C	32	2.5	2.5	Lead-Free TQFP	48	32	C
	LC4032B-5TN48C	32	2.5	5	Lead-Free TQFP	48	32	C
	LC4032B-75TN48C	32	2.5	7.5	Lead-Free TQFP	48	32	C
	LC4032B-25TN44C	32	2.5	2.5	Lead-Free TQFP	44	30	C
	LC4032B-5TN44C	32	2.5	5	Lead-Free TQFP	44	30	C
	LC4032B-75TN44C	32	2.5	7.5	Lead-Free TQFP	44	30	C
LC4064B	LC4064B-25TN100C	64	2.5	2.5	Lead-Free TQFP	100	64	C
	LC4064B-5TN100C	64	2.5	5	Lead-Free TQFP	100	64	C
	LC4064B-75TN100C	64	2.5	7.5	Lead-Free TQFP	100	64	C
	LC4064B-25TN48C	64	2.5	2.5	Lead-Free TQFP	48	32	C
	LC4064B-5TN48C	64	2.5	5	Lead-Free TQFP	48	32	C
	LC4064B-75TN48C	64	2.5	7.5	Lead-Free TQFP	48	32	C
	LC4064B-25TN44C	64	2.5	2.5	Lead-Free TQFP	44	30	C
	LC4064B-5TN44C	64	2.5	5	Lead-Free TQFP	44	30	C
	LC4064B-75TN44C	64	2.5	7.5	Lead-Free TQFP	44	30	C
LC4128B	LC4128B-27TN128C	128	2.5	2.7	Lead-Free TQFP	128	92	C
	LC4128B-5TN128C	128	2.5	5	Lead-Free TQFP	128	92	C
	LC4128B-75TN128C	128	2.5	7.5	Lead-Free TQFP	128	92	C
	LC4128B-27TN100C	128	2.5	2.7	Lead-Free TQFP	100	92	C
	LC4128B-5TN100C	128	2.5	5	Lead-Free TQFP	100	92	C
	LC4128B-75TN100C	128	2.5	7.5	Lead-Free TQFP	100	92	C
LC4256B	LC4256B-3FTN256AC	256	2.5	3	Lead-Free ftBGA	256	128	C
	LC4256B-5FTN256AC	256	2.5	5	Lead-Free ftBGA	256	128	C
	LC4256B-75FTN256AC	256	2.5	7.5	Lead-Free ftBGA	256	128	C
	LC4256B-3FTN256BC	256	2.5	3	Lead-Free ftBGA	256	160	C
	LC4256B-5FTN256BC	256	2.5	5	Lead-Free ftBGA	256	160	C
	LC4256B-75FTN256BC	256	2.5	7.5	Lead-Free ftBGA	256	160	C
	LC4256B-3FN256AC[1]	256	2.5	3	Lead-Free fpBGA	256	128	C
	LC4256B-5FN256AC[1]	256	2.5	5	Lead-Free fpBGA	256	128	C
	LC4256B-75FN256AC[1]	256	2.5	7.5	Lead-Free fpBGA	256	128	C
	LC4256B-3FN256BC[1]	256	2.5	3	Lead-Free fpBGA	256	160	C
	LC4256B-5FN256BC[1]	256	2.5	5	Lead-Free fpBGA	256	160	C
	LC4256B-75FN256BC[1]	256	2.5	7.5	Lead-Free fpBGA	256	160	C
	LC4256B-3TN176C	256	2.5	3	Lead-Free TQFP	176	128	C
	LC4256B-5TN176C	256	2.5	5	Lead-Free TQFP	176	128	C
	LC4256B-75TN176C	256	2.5	7.5	Lead-Free TQFP	176	128	C
	LC4256B-3TN100C	256	2.5	3	Lead-Free TQFP	100	64	C
	LC4256B-5TN100C	256	2.5	5	Lead-Free TQFP	100	64	C
	LC4256B-75TN100C	256	2.5	7.5	Lead-Free TQFP	100	64	C

ispMACH 4000V (3.3V) Lead-Free Commercial Devices

Device	Part Number	Macrocells	Voltage	t_{PD}	Package	Pin/Ball Count	I/O	Grade
LC4032V	LC4032V-25TN48C	32	3.3	2.5	Lead-free TQFP	48	32	C
	LC4032V-5TN48C	32	3.3	5	Lead-free TQFP	48	32	C
	LC4032V-75TN48C	32	3.3	7.5	Lead-free TQFP	48	32	C
	LC4032V-25TN44C	32	3.3	2.5	Lead-free TQFP	44	30	C
	LC4032V-5TN44C	32	3.3	5	Lead-free TQFP	44	30	C
	LC4032V-75TN44C	32	3.3	7.5	Lead-free TQFP	44	30	C
LC4064V	LC4064V-25TN100C	64	3.3	2.5	Lead-free TQFP	100	64	C
	LC4064V-5TN100C	64	3.3	5	Lead-free TQFP	100	64	C
	LC4064V-75TN100C	64	3.3	7.5	Lead-free TQFP	100	64	C
	LC4064V-25TN48C	64	3.3	2.5	Lead-free TQFP	48	32	C
	LC4064V-5TN48C	64	3.3	5	Lead-free TQFP	48	32	C
	LC4064V-75TN48C	64	3.3	7.5	Lead-free TQFP	48	32	C
	LC4064V-25TN44C	64	3.3	2.5	Lead-free TQFP	44	30	C
	LC4064V-5TN44C	64	3.3	5	Lead-free TQFP	44	30	C
	LC4064V-75TN44C	64	3.3	7.5	Lead-free TQFP	44	30	C
LC4128V	LC4128V-27TN144C	128	3.3	2.7	Lead-free TQFP	144	96	C
	LC4128V-5TN144C	128	3.3	5	Lead-free TQFP	144	96	C
	LC4128V-75TN144C	128	3.3	7.5	Lead-free TQFP	144	96	C
	LC4128V-27TN128C	128	3.3	2.7	Lead-free TQFP	128	92	C
	LC4128V-5TN128C	128	3.3	5	Lead-free TQFP	128	92	C
	LC4128V-75TN128C	128	3.3	7.5	Lead-free TQFP	128	92	C
	LC4128V-27TN100C	128	3.3	2.7	Lead-free TQFP	100	64	C
	LC4128V-5TN100C	128	3.3	5	Lead-free TQFP	100	64	C
	LC4128V-75TN100C	128	3.3	7.5	Lead-free TQFP	100	64	C